L Number	Hits	Search Text	DB	Time stamp
1	204	plot\$6 same cut\$6 same sensor	USPAT;	2004/10/31 16:08
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
2	6	(plot\$6 same cut\$6 same sensor) same master	USPAT;	2004/10/31 16:07
1			US-PGPUB;	
			EPO; JPO;	
		2 . 46	DERWENT	0004/10/21 16 17
3	1430089	[ <del>-</del>	USPAT;	2004/10/31 16:17
		semiconductor	US-PGPUB; EPO; JPO;	
			DERWENT	
4	13392	(plot\$6 same cut\$6 same master same	USPAT;	2004/10/31 16:15
4	13392	substrate semiconductor) same tft	US-PGPUB;	2001/10/31 10:13
		Substitute Semitoriductory Sume tre	EPO; JPO;	
			DERWENT	
5	561	((plot\$6 same cut\$6 same master same	USPAT;	2004/10/31 16:16
_		substrate semiconductor) same tft) same	US-PGPUB;	
		(image with sensor)	EPO; JPO;	
1			DERWENT	
6	514	((plot\$6 same cut\$6 same master same	USPAT;	2004/10/31 16:17
		substrate semiconductor) same tft) same	US-PGPUB;	
		(image adj sensor)	EPO; JPO;	
			DERWENT	
7	0	F	USPAT;	2004/10/31 16:18
		substrate) same semiconductor	US-PGPUB;	
			EPO; JPO;	
	_	1.1.00	DERWENT	0004/10/27 16 10
8	1	1 -	USPAT;	2004/10/31 16:19
		substrate) same semiconductor	US-PGPUB; EPO; JPO;	
			DERWENT	
9	1	plot\$6 same cut\$6 same (master with	USPAT;	2004/10/31 16:20
	_	substrate) same tft	US-PGPUB;	2001, 10, 31 10,120
Ī		passerace, same ere	EPO; JPO;	
			DERWENT	
10	2	cut\$6 same (master with substrate) same tft	USPAT;	2004/10/31 16:26
1			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
11	38	l ·	USPAT;	2004/10/31 16:26
		semiconductor	US-PGPUB;	
			EPO; JPO;	
10	_	( subt( some (master with substrate) some	DERWENT	2004/10/21 16:07
12	1	1 , ,	USPAT; US-PGPUB;	2004/10/31 16:27
		semiconductor) and tft	EPO; JPO;	
			DERWENT	
13	0	( cut\$6 same (master with substrate) same	USPAT;	2004/10/31 16:27
		semiconductor) and 1cd	US-PGPUB;	
İ			EPO; JPO;	
			DERWENT	
14	19	( cut\$6 same (master with substrate) same	USPAT;	2004/10/31 16:28
		semiconductor) and (liquid adj crystal)	US-PGPUB;	
			EPO; JPO;	
L	L		DERWENT	

09/490,502